Ordering number: EN3236

PNP Epitaxial Planar Silicon Transistor



2SB1405

# **General Driver Applications**

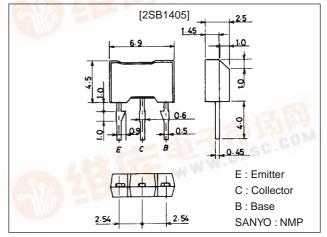
#### **Features**

- · Darlington connection.
- · High DC current gain.
- · Large current capacity, wide ASO.

## **Package Dimensions**

unit:mm

2064



## **Specifications**

## Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		-80	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		-50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>	p 400	-10	V
Collector Current	IC	and the	-0.7	Α
Collector Current (Pulse)	ICP	- A.D. (1922 14)	-2	Α
Collector Dissipation	PC	AND LITTLE W	1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

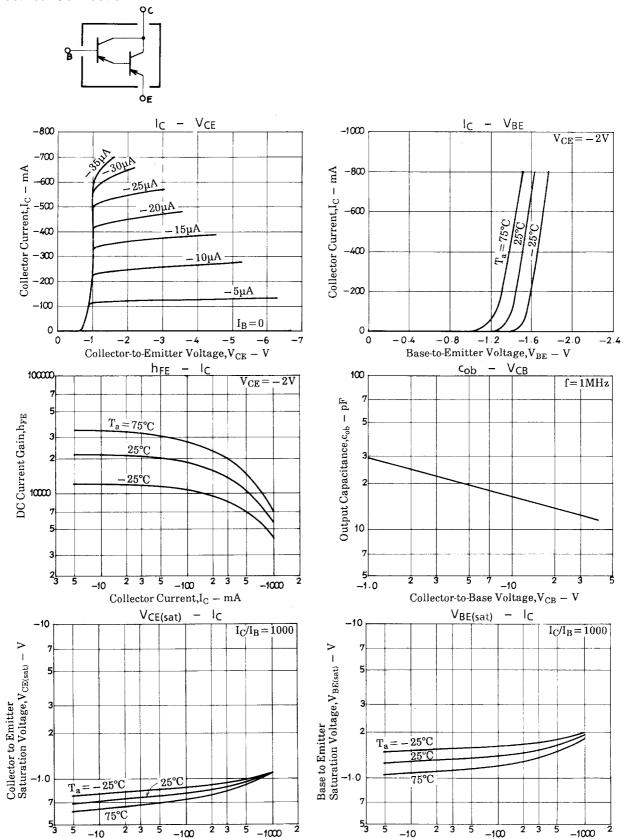
Parameter	Symbol	Conditions	Ratings			Unit
		Conditions		typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =-40V, I <sub>E</sub> =0			-100	nA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =-8V, I <sub>C</sub> =0			-100	nA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =-2V, I <sub>C</sub> =-50mA	5000			111
	h <sub>FE</sub> 2	V <sub>CE</sub> =-2V, I <sub>C</sub> =-500mA	3000		)	Adv.
Gain-Bandwidth Product	fT	V <sub>CE</sub> =-5V, I <sub>C</sub> =-50mA	400	170	40-1	MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =-10V, f=1MHz		18		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-100mA, I <sub>B</sub> =-0.1mA	77	-0.8	-1.2	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =-100mA, I <sub>B</sub> =-0.1mA		-1.4	-2.0	V

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Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Oill
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =-10μΑ, I <sub>E</sub> =0	-80			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =-1mA, R <sub>BE</sub> =∞	<i>–</i> 50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =-10μΑ, I <sub>C</sub> =0	-10			V

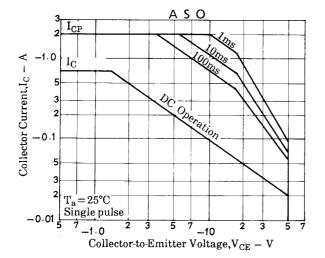
### **Electrical Connection**

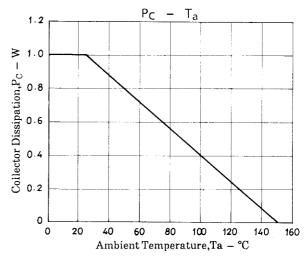


 $Collector\ Current, I_C-mA$ 

-10

 $Collector\ Current, I_C-mA$ 





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